

Specification of MEMS Microphone (RoHS Compliance & Halogen Free)

Customer Name :
 Customer Model :
 Goermicro Model : SD18OB261-050

Goermicro	CUSTOMER APPROVAL
<u>DESIGN</u> <u>Pauline Zhao 2021.09.23</u>	
<u>CHKD</u> <u>Hubery Zhang 2021.09.23</u>	
<u>STANDARD</u> <u>Angela Kong 2021.09.23</u>	
<u>APVD</u> <u>Roy Wang 2021.09.23</u>	



Tel : + 86 536 8521234
 E- Mail : goermicro@goermicro.com
 Website: <http://www.goermicro.com>
 Address: No.268 Dongfang Road, High-Tech Industry
 Development District, Weifang, Shandong, P.R.C.

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1 Security Warning

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2 Publication History

Version	Description	Date	Author	Approved
1.0	New Design	2018.08.31	Tyler	Sunny
2.0	Update Product Appearance	2019.07.30	Tyler	Sunny
3.0	Update Acoustical&Electrical Characteristics &Package Information	2019.11.28	Tyler	Sunny
4.0	Update Document Template	2021.03.31	Zamp	Jenny
5.0	Update Acoustical Performance and Curve in Section 3	2021.06.01	Zamp	Jenny
6.0	Update the Logo to Goermicro	2021.08.20	Pauline	Roy
7.0	Add 1.536MHz Mode Performance	2021.09.23	Pauline	Roy

Contents

1	Introduction	4
2	Test Condition	4
3	Acoustical and Electrical Characteristics	4
3.1	Standard Performance Mode	4
3.2	Frequency Response Curve and Limits	5
3.3	Low Power Mode	6
3.4	Performance Curve	6
3.5	General Microphone Specification	7
3.6	Micronphone Interface Specifications	7
4	Measurement Circuit	9
5	Test Setup Drawing	9
6	Mechanical Characteristics	10
6.1	Appearance Drawing	10
6.2	Weight	10
7	Reliability Test	11
7.1	Vibration Test	11
7.2	Drop Test	11
7.3	Temperature Test	11
7.4	Humidity Test	11
7.5	Mechanical Shock Test	11
7.6	Thermal Shock Test	11
7.7	Reflow Test	11
7.8	ESD Shock Test	11
8	Package	12
8.1	Tape Specification	12
8.2	Reel Dimension	13
8.3	The Content of Box	13
8.4	Packing Explain	14
9	Storage and Transportation	14
10	Land Pattern Recommendation	15
10.1	The Pattern of MIC Pad	15
10.2	Recommended Soldering Surface Land Pattern	15
11	Soldering Recommendation	16
11.1	Soldering Machine Condition	16
11.2	The Drawing and Dimension of Nozzle	16
11.3	Reflow Profile	17
12	Cautions When Using MEMS MIC	18
12.1	Board Wash Restrictions	18
12.2	Sound Hole Productions	18
12.3	Ultrasonic Restrictions	18
13	Output Inspection Standard	18

1 Introduction:

MEMS MIC which is able to endure reflow temperature up to 260°C for 50 seconds can be used in SMT process. It is widely used in telecommunication and electronics device such as mobile phone, laptop computers, and other portable electronic devices etc.

2 Test Condition (L=50 cm)

StandardConditions (As IEC 60268-4)	Temperature	Humidity	Air pressure
Environment Conditions	+15°C~+35°C	25%RH~75%RH	86kPa~106kPa
Basic Test Conditions	+20°C±2°C	60%RH~70%RH	86kPa~106kPa

3 Acoustical and Electrical Characteristics

3.1 Standard Performance Mode

(Test Condition: $V_{DD}=1.8V$, $f_{CLK}=2.4MHz$, Decimation=64X)

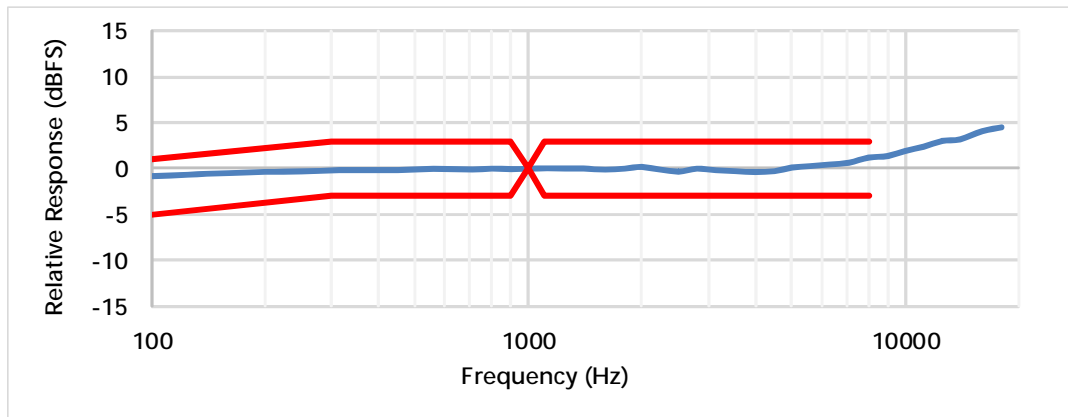
Item	Symbol	Test Conditions	Min	Typ	Max	Unit
Sensitivity	S	f=1kHz, P _{in} =1Pa	-27	-26	-25	dBFS (Note 1)
Current Consumption (Note 2)	I	No load	-	560	650	μA
S/N Ratio	SNR	f=1kHz, P _{in} =1Pa A-Weighted Curve	-	65	-	dB
Distortion	THD	THD<1% @1kHz	-	111	-	dB SPL
Acoustic Overload Point	AOP	10% THD @1 kHz	-	120	-	dB SPL
Power Supply Rejection	PSR	100mVpp squarewave@217Hz	-	-89	-	dBFS
Low Frequency Roll-off	LFRO	-3dB corner refrence to 1kHz sensitivity	-	40	-	Hz
High Frequency Flatness		+3dB refrence to 1kHz sensitivity	-	12.5	-	KHz

(Test Condition: $V_{DD}=1.8V$, $f_{CLK}=1.536MHz$, Decimation=64X)

Item	Symbol	Test Conditions	Min	Typ	Max	Unit
Sensitivity	S	f=1kHz, P _{in} =1Pa	-27	-26	-25	dBFS (Note 1)
Current Consumption (Note 2)	I	No load	-	480	580	μA
S/N Ratio	SNR	f=1kHz, P _{in} =1Pa A-Weighted Curve	-	65	-	dB
Distortion	THD	THD<1% @1kHz	-	111	-	dB SPL
Acoustic Overload Point	AOP	10% THD @1 kHz	-	120	-	dB SPL
Power Supply Rejection	PSR	100mVpp squarewave@217Hz	-	-89	-	dBFS
Low Frequency Roll-off	LFRO	-3dB corner reference to 1kHz sensitivity	-	40	-	Hz

3.2 Frequency Response Curve and Limits

(Test Condition: $V_{DD}=1.8V$, $f_{CLK}=2.4MHz$, Decimation Rate=64x)



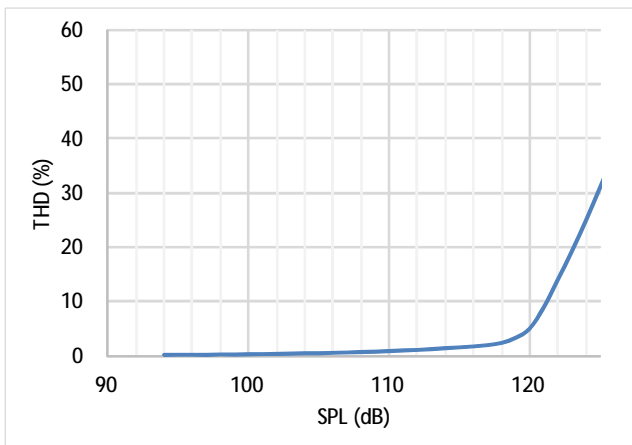
Frequency(Hz)	100	300	500	900	1100	3000	8000
Upper Limit(dBFS)	1	3	3	3	3	3	3
Lower Limit(dBFS)	-5	-3	-3	-3	-3	-3	-3

3.3 Low Power Mode (Test Condition: $V_{DD}=1.8V$, $f_{CLK}=768kHz$)

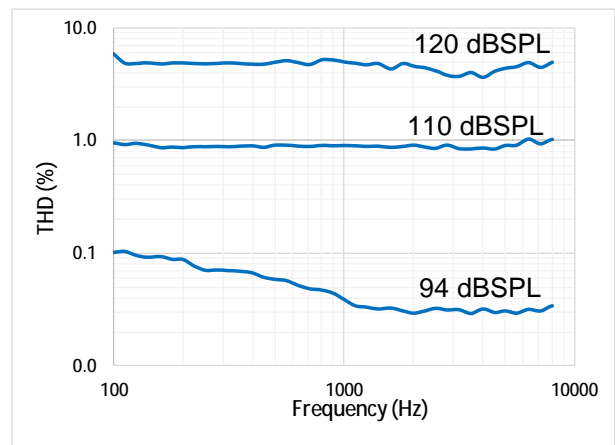
Item	Symbol	Test Conditions	Min	Typ	Max	Unit
Sensitivity	S	$f=1kHz$, $P_{in}=1Pa$	-27	-26	-25	dBFS (Note 1)
Current Consumption (Note 2)	I	$f_{clk}=768kHz$	-	230	300	μA
S/N Ratio	SNR	$f=1kHz$, $P_{in}=1Pa$ A-Weighted Curve	-	65	-	dB
Distortion	THD	THD<1% @1kHz	-	111	-	dB SPL
Acoustic Overload Point	AOP	10% THD @1 kHz	-	119	-	dB SPL
Power Supply Rejection	PSR	100mVpp squarewave@217Hz	-	-88	-	dBFS
Low Frequency Roll-off	LFRO	-3dB corner refrence to 1kHz sensitivity	-	40	-	Hz

3.4 Performance Curve

Typical THD vs SPL
Standard Mode $V_{DD}=1.8V$, $f_{CLK}=2.4MHz$



Typical THD vs Frequency
Standard Mode $V_{DD}=1.8V$, $f_{CLK}=2.4MHz$



3.5 General Microphone Specifications

Item	Symbol	Test Conditions	Min	Typ	Max	Unit
Supply Voltage	V_{DD}	-	1.62	1.8	3.6	V
Clock Frequency Range	Standby Mode	-	-	-	330	kHz
	Low Power Mode	-	450	768	850	kHz
	Standard Mode	-	-	1.38	1.536	1.7
-		-	2.1	2.4	2.6	MHz
	-	-	2.9	3.072	3.3	MHz
Directivity	-	-	Omni-directional			
Polarity	-	Increasing Sound	Increasing density of 1's			
Data Format	-		$\frac{1}{2}$ Cycle PDM 1bit			
Short Circuit Current	I_{sc}	Grounded Data Pin	1	-	20	mA
Output Load Capacitance on DATA	C_{load}	-	-	-	100	pF
VDD ramp up time		Time until $V_{DD} \geq V_{DD_min}$.	-	-	50	ms
Start-up Time		Time to start up in either modes (Low Power- and Normal Mode) after V_{DD} and $CLOCK$ have been applied.	-	-	50	ms
Mode-Change Time		Time to switch between modes	-	-	50	ms

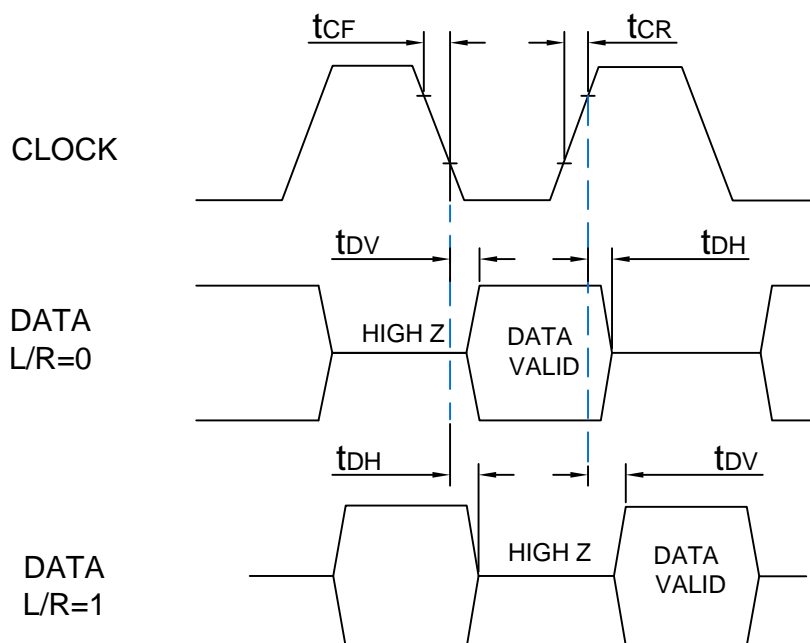
3.6 Microphone Interface Specifications

Item	Symbol	Test Conditions	Min	Typ	Max	Unit
Logic Input High	V_{IH}	-	$0.65 \cdot V_{DD}$	-	$V_{DD} + 0.3$	V
Logic Input Low	V_{IL}	-	-0.3	-	$0.35 \cdot V_{DD}$	V
Logic Output High	V_{OH}	-	$0.7 \cdot V_{DD}$	-	-	V
Logic Output Low	V_{OL}	-	-	-	$0.3 \cdot V_{DD}$	V
Clock Duty Cycle	-	$f_{CLK} \leq 2.7\text{MHz}$	45	-	55	%
	-	$f_{CLK} > 2.7\text{MHz}$	48	-	52	%
Clock Rise/Fall Time	t_{CF}, t_{CR}	-	-	-	13	ns
Delay Time for Valid Data (Note 3)	t_{DV}	Max C_{LOAD} for t_{DV}	-	-	100	ns
Delay Time for High Z	t_{DH}	-	5	-	30	ns

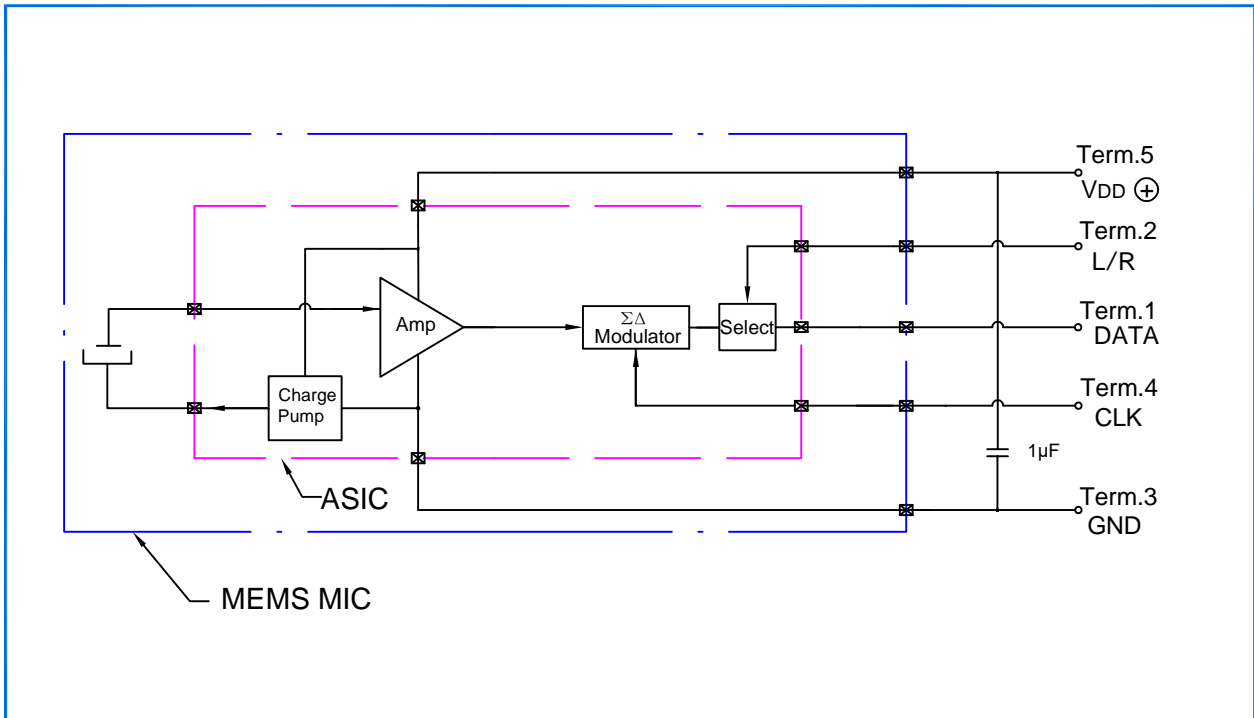
Note 1. $dBFS = 20 \times \log(A/B)$ where A is the level of the signal, B is the level that corresponds to Full-scale level.

Note 2. The current consumption depends on the applied Clock Frequency and the load on the DATA output.

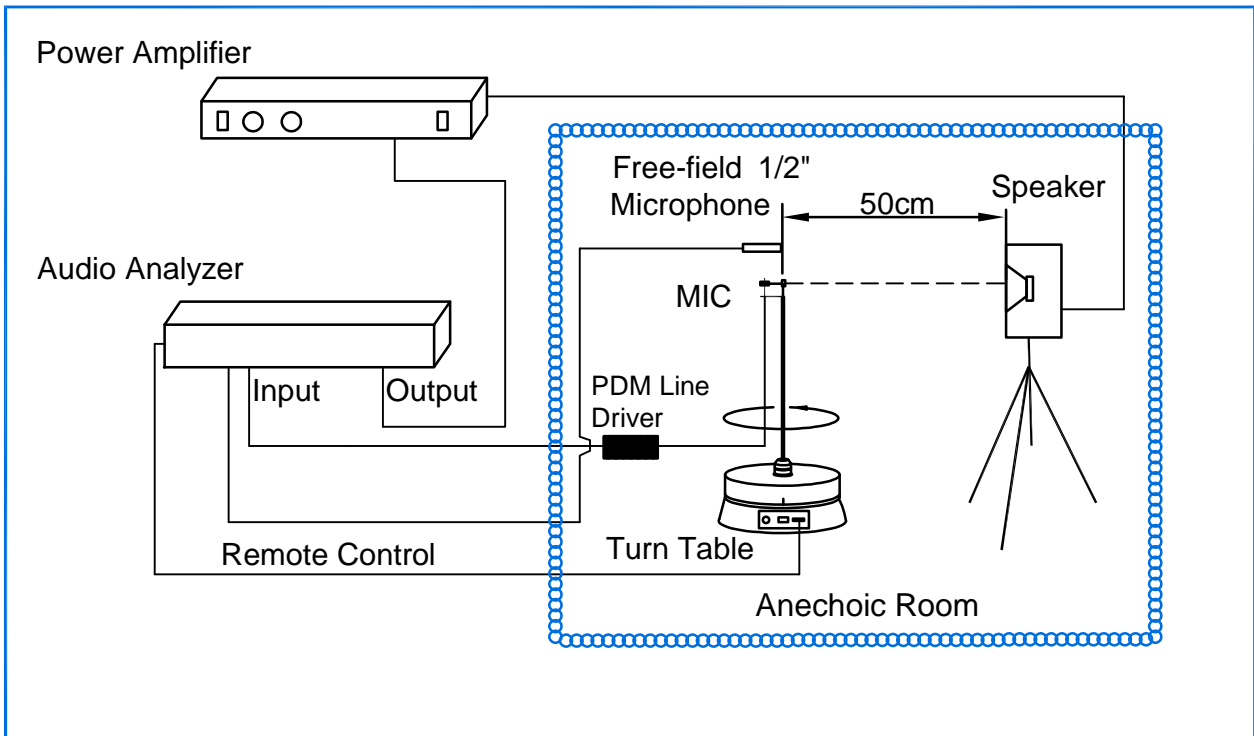
Note 3. Timing



4 Measurement Circuit

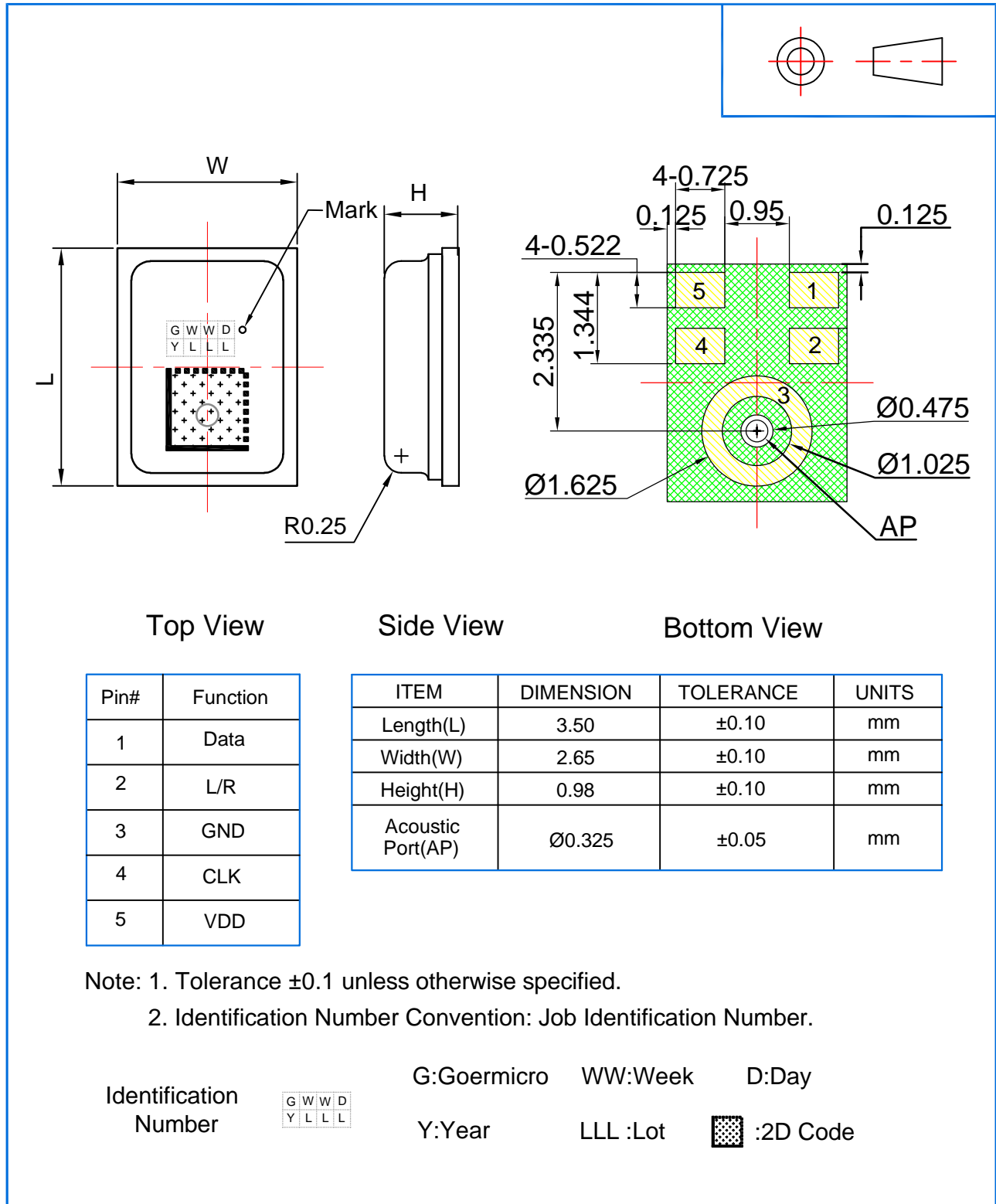


5 Test Setup Drawing



6 Mechanical Characteristics

6.1 Appearance Drawing (Unit: mm)



6.2 Weight

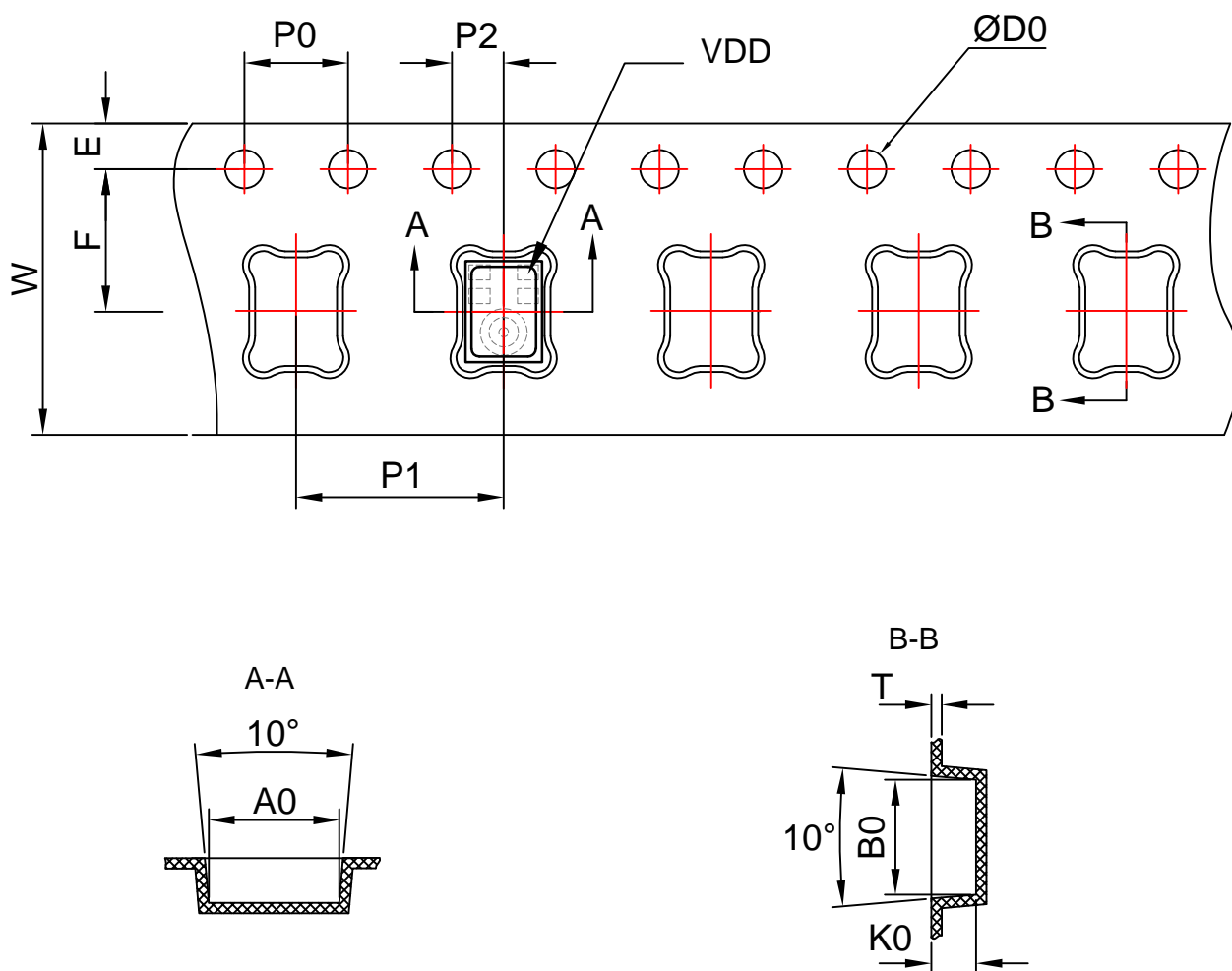
The weight of the MIC is Less than 0.05g.

7 Reliability Test

<p>7.1 Vibration Test</p>	<p>To be no interference in operation after vibrations, 4 cycles, from 20 to 2000HZ in each direction (X,Y,Z), 48min, user acceleration of 20g, sensitivity should vary within ± 3dBFS from initial sensitivity. (The measurement to be done after 2 hours of conditioning at $+15^{\circ}\text{C} \sim +35^{\circ}\text{C}$, R.H 25% \sim 75%)</p>
<p>7.2 Drop Test</p>	<p>To be no interference in operation after dropped to 1.0 cm steel plate 12 times from 1.5 meter height in state of JIG,JIG weight of 100 g, sensitivity should vary within ± 3dBFS from initial sensitivity. (The measurement to be done after 2 hours of conditioning at $+15^{\circ}\text{C} \sim +35^{\circ}\text{C}$, R.H 25% \sim 75%)</p>
<p>7.3 Temperature Test</p>	<p>a) After exposure at $+125^{\circ}\text{C}$ for 200h, sensitivity should vary within ± 3dBFS from initial sensitivity. (The measurement to be done after 2h of conditioning at $+15^{\circ}\text{C} \sim +35^{\circ}\text{C}$, R.H 25% \sim 75%) b) After exposure at -40°C for 200h, sensitivity should vary within ± 3dBFS from initial sensitivity. (The measurement to be done after 2 hours of conditioning at $+15^{\circ}\text{C} \sim +35^{\circ}\text{C}$, R.H 25% \sim 75%)</p>
<p>7.4 Humidity Test</p>	<p>After exposure at $+85^{\circ}\text{C}$ and 85% relative humidity for 200 hours, sensitivity should vary within ± 3dBFS from initial sensitivity. (The measurement to be done after 2 hours of conditioning at $+15^{\circ}\text{C} \sim +35^{\circ}\text{C}$, R.H 25% \sim 75%)</p>
<p>7.5 Mechanical Shock Test</p>	<p>Then subject samples to three one-half sine shock pulses (3000 g for 0.3 milliseconds) in each direction (for six axes in total) along each of the three mutually perpendicular axes for a total of 18 shocks, sensitivity should vary within ± 3dBFS from initial sensitivity. (The measurement to be done after 2 hours of conditioning at $+15^{\circ}\text{C} \sim +35^{\circ}\text{C}$, R.H 25% \sim 75%)</p>
<p>7.6 Thermal Shock Test</p>	<p>After exposure at -40°C for 30min, at $+125^{\circ}\text{C}$ for 30min (change time 20 seconds) 32 cycles, sensitivity should vary within ± 3dBFS from initial sensitivity. (The measurement to be done after 2 hours of conditioning at $+15^{\circ}\text{C} \sim +35^{\circ}\text{C}$, R.H 25% \sim 75%)</p>
<p>7.7 Reflow Test</p>	<p>Adopt the reflow curve of item 12.3, after three reflows, sensitivity should vary within ± 3dBFS from initial sensitivity. (The measurement to be done after 2 hours of conditioning at $+15^{\circ}\text{C} \sim +35^{\circ}\text{C}$, R.H 25% \sim 75%)</p>
<p>7.8 ESD Shock Test</p>	<p>Under $C=150\text{pF}$, $R=330\text{ohm}$. Tested to $\pm 8\text{KV}$ contact to the case and tested to $\pm 2\text{kV}$ contact to I/O terminals.10 times. Grounding. Sensitivity should vary within ± 3dBFS from initial sensitivity. (The measurement to be done after 2 hours of conditioning at $+15^{\circ}\text{C} \sim +35^{\circ}\text{C}$, R.H.25% \sim 75%)</p>

8 Package

8.1 Tape Specification



The Dimensions as Follows:

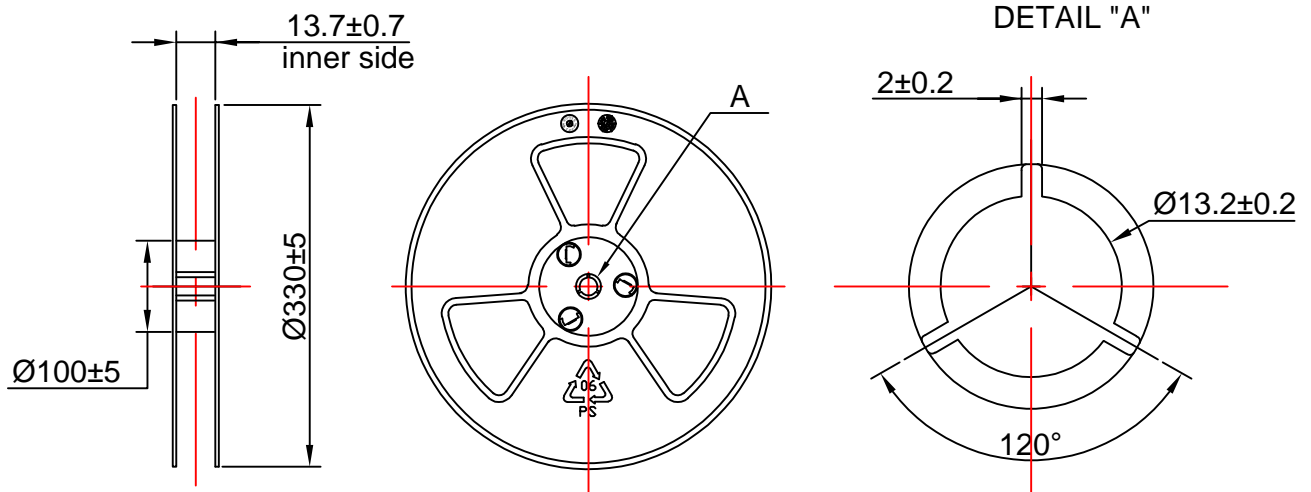
ITEM	W	E	F	ØD0	K0
DIM(mm)	12.0±0.30	1.75±0.10	5.5±0.05	1.50 ^{+0.10} ₀	1.30±0.10
ITEM	P0	10P0	P1	A0	B0
DIM(mm)	4.00±0.10	40.00±0.20	8.00±0.10	2.85±0.05	3.75±0.05
ITEM	P2	T			
DIM(mm)	2.00±0.05	0.30±0.05			

8.2 Reel Dimension

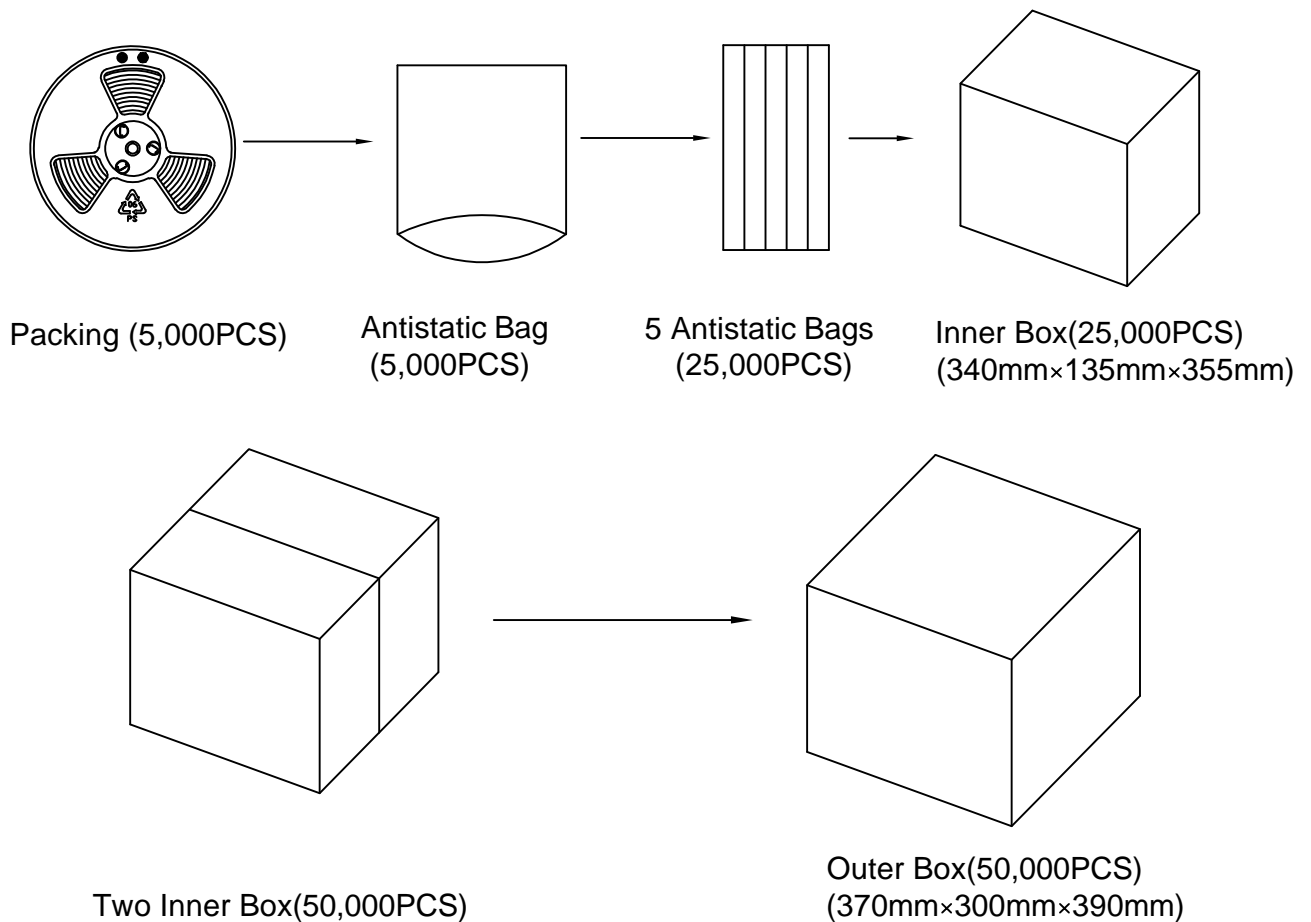
7" reel for sample stage

13" reel will be provided for the mass production stage

The following is 13" reel dimensions (unit:mm)

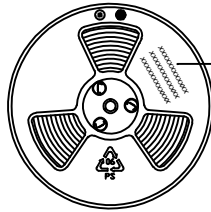


8.3 The Content of Box(13" reel)



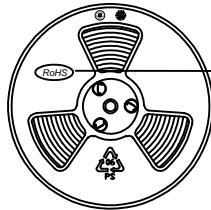
8.4 Packing Explain

8.4.1 The Label Content of the Reel



The Content Includes:
Product type, Lot, Customer P/N;
and other essential information such as
Quantity, Date etc.

8.4.2 The RoHS Label



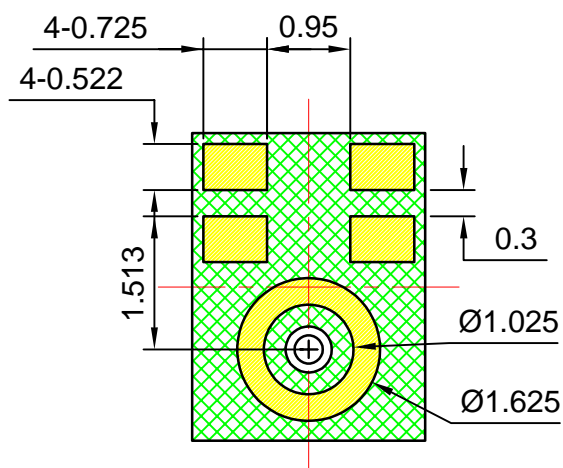
RoHS Compliance &
Halogen Free Mark

9 Storage and Transportation

- 9.1 Keep MEMS MIC in warehouse with less than 75% humidity and without sudden temperature change, acid air, any other harmful air or strong magnetic field. Recommend storage period no more than 1 year and floor life(out of bag) at factory no more than 4 weeks.
- 9.2 The MEMS MIC with normal pack can be transported by ordinary conveyances. Please protect products against moist, shock, sunburn and pressure during transportation.
- 9.3 Storage Temperature Range: $-40^{\circ}\text{C} \sim +70^{\circ}\text{C}$
- 9.4 Operating Temperature Range: $-40^{\circ}\text{C} \sim +100^{\circ}\text{C}$

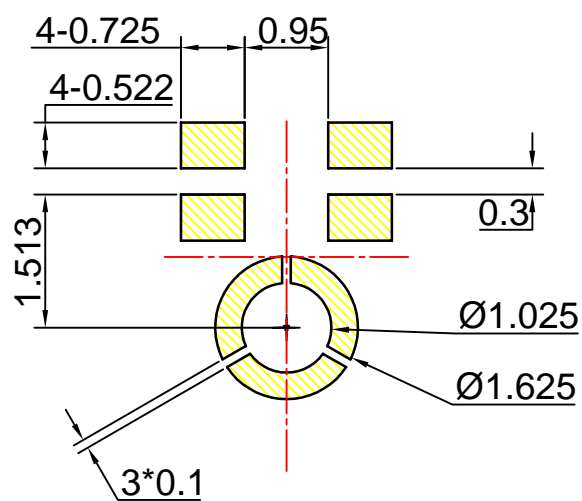
10 Land Pattern Recommendation

10.1 The Pattern of MIC Pad(Unit:mm)



10.2 Recommended Soldering Surface Land Pattern (Unit:mm)

Recommended the size of solder stencil pattern area is $>80\%$ of MIC pads, as below, and the stencil thickness suggestion is 0.1 mm.

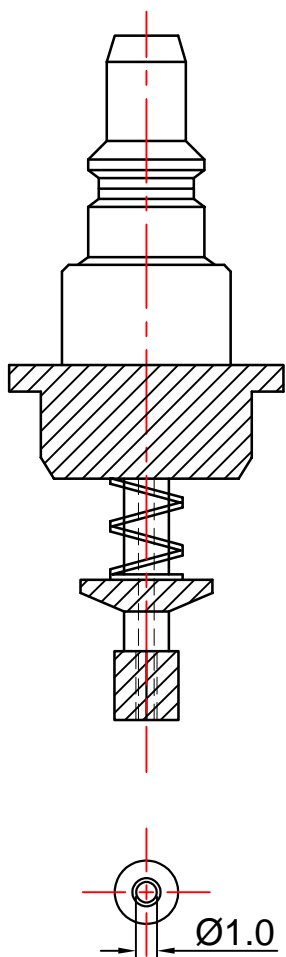


11 Soldering Recommendation

11.1 Soldering Machine Condition

Temperature Control	8 zones
Heater Type	Hot Air
Solder Type	Lead-free

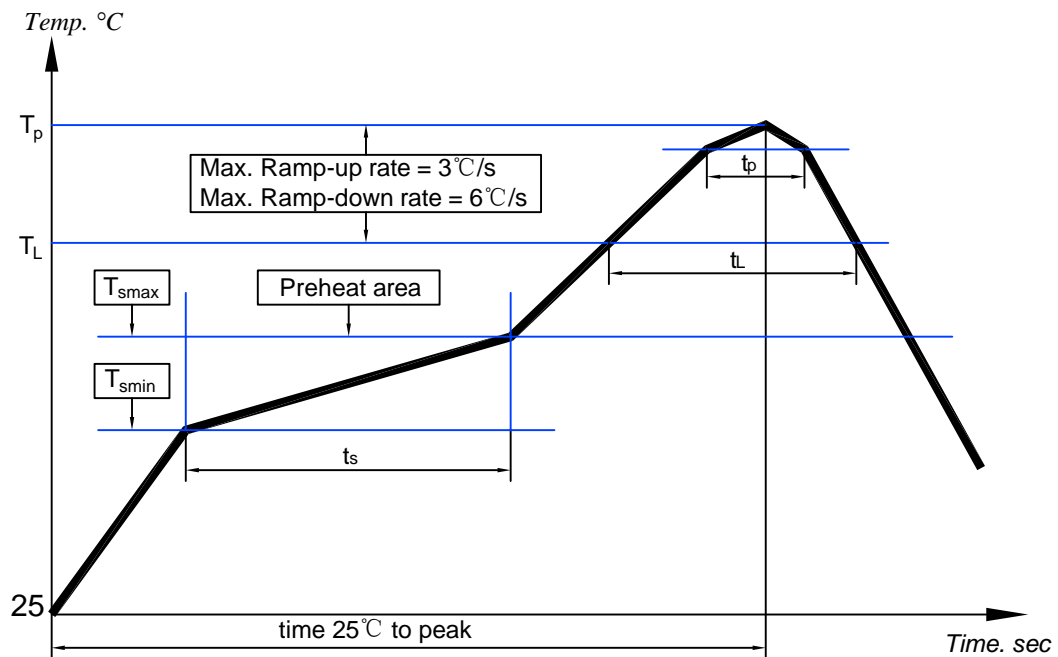
11.2 The Drawing and Dimension of Nozzle



Inside Diameter: 1.0mm;

Please don't vacuum over the acoustic port directly.
Please don't blow the acoustic port directly.

11.3 Reflow Profile



Key Features of The Profile:

Average Ramp-up rate(T_{smax} to T_p)	3°C/s max.
Preheat : Temperature Min(T_{smin}) Temperature Max(T_{smax}) Time(T_{smin} to T_{smax})(t_s)	150°C 200°C 60~180s
Time maintained above : Temperature(T_L) Time(t_L)	217°C 60~150s
Peak Temperature(T_p)	260°C
Time within 5°C of actual Peak Temperature(t_p) :	30~40s
Ramp-down rate(T_p to T_{smax})	6°C/s max
Time 25°C to Peak Temperature	8min max

When MEMS MIC is soldered on PCB, the reflow profile is set according to solder paste and the thickness of PCB etc.

12 Cautions When Using MEMS MIC

12.1 Board Wash Restrictions

It is very important not to wash this silicon microphone, otherwise this could damage the microphone.

12.2 Sound Hole Protection

It is very important not to operate vacuum and air blow into sound hole(without any covering over sound holes), otherwise this could damage the microphone.

And it is necessary to be careful about foreign substances into sound hole inside silicon microphone.

It is very important to keep the distance between MIC and cutting area as far as possible to avoid the cutting stive entering into MEMS, Otherwise this could contaminate the MIC.

12.3 Ultrasonic Restrictions

It is very important not to use ultrasonic process. otherwise this could damage the microphone.

13 Output Inspection Standard

Output inspection standard is executed according to <<ISO2859-1:1999>>.